GigaDevice Semiconductor Inc.

Device limitations of GD32F47x/F42x

Errata Sheet

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1. Introduction

This document applies to GD32F47x/F42x product series, as shown in ***Table 1-1. Applicable products***. It provides the technical details that need to be paid attention to in the process of using GD32 MCU, as well as solutions to related problems.

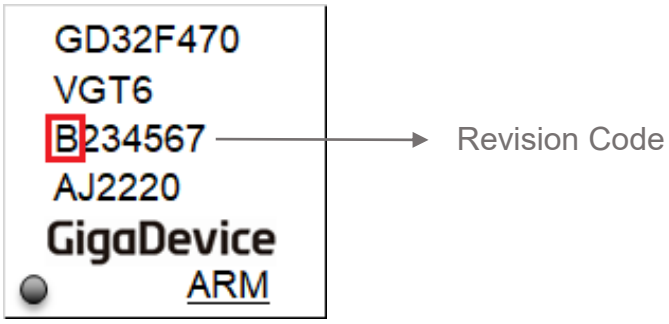
Table 1-1. Applicable products

Type	Part Numbers
MCU	GD32F425xx series
	GD32F427xx series
	GD32F470xx series

1.1. Revision identification

The device revision can be determined by the mark on the top of the package. The 1st code on the line 3 of the mark represents product revision code. As the picture shown in ***Figure 1-1. Device revision code of GD32F47x/F42x***.

Figure 1-1. Device revision code of GD32F47x/F42x



1.2. Summary of device limitations

The device limitations of GD32F47x/F42x are shown in ***Table 1-2. Device limitations***, please refer to section 2 for more details.

Table 1-2. Device limitations

Module	Limitations	Workaround	
		Rev. Code A	Rev. Code B
PMU	***Standby mode cannot be waked up due to frequent wakeup signals before or after entering standby mode***	N	N
GPIO	***IO compensation invalidation***	N	--
ADC	***ADC samples abnormally when using both 6-***	Y	Y

Module	Limitations	Workaround	
		Rev. Code A	Rev. Code B
	bit sampling resolution and MSB alignment		
	ADC alignment mode is not consistent with the user manual description	Y	Y
RTC	*Calibrate abnormally when using both smooth digital calibration and FREQI calibration*	Y	Y
TIMER	*The shadow preloaded value takes effect only on the rising edge of the counter after modification*	N	N
	Count error when timer works at single pulse mode	Y	Y
USART	*Mute mode can be waked up as long as the USART_CTL0 register is operated after mute mode is enabled*	Y	Y
I2C	*I2C_FCTL register is only configurable on GD32F470xx*	N	N
SDIO	*Do not support low power mode*	N	N
EXMC	*Auto refresh function of SDRAM controller is influenced by other EXMC controller*	N	N
ENET	*Data reception faults in MII mode*	Y	Y
	Reception data frame is dropped when enable hardware checksum and the header checksum is 0x0000	Y	Y
Core	*VDIV or VSQRT instructions might not complete correctly when very short ISRs are used*	Y	Y

Note:

Y = Limitation present, workaround available

N = Limitation present, no workaround available

'--' = Limitation fixed

2. Descriptions of device limitations

2.1. PMU

2.1.1. Standby mode cannot be waked up due to frequent wakeup signals before or after entering standby mode

Description & impact

When reset the internal signal STBY_CTL to enter to standby mode, if the T_{glitch} is smaller than 100ns, which will cause the mcu cannot be waked up. The narrow glitch will result in incorrect Vcore voltage.

Note: The T_{glitch} is the time between STBY_CTL low level and the wakeup signal (PA0 high level)

Workarounds

Not available.

2.2. GPIO

2.2.1. IO compensation invalidation

Description & impact

IO compensation function is invalided.

Workarounds

Not available.

2.3. ADC

2.3.1. ADC samples abnormally when using both 6-bit sampling resolution and MSB alignment

Description & impact

ADC samples abnormally when using both 6-bit sampling resolution and MSB alignment mode.

Workarounds

Use LSB alignment mode or use 8-bit sampling resolution.

2.3.2. ADC alignment mode is not consistent with the user manual description

Description & impact

ADC alignment mode is not consistent with the user manual description.

Workarounds

The right alignment mode description is as follow:

Table 2-1. Alignment mode of routine conversion

Alignment	Resolution	bit15	bit14	bit13	bit12	bit11	bit10	bit9	bit8	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0
LSB	12bit	0x0				data											
	10bit	0x0				data										0x0	
	8bit	0x0				data								0x0			
	6bit	0x0				data						0x0					
MSB	12bit	data												0x0			
	10bit	data										0x0					
	8bit	data								0x0							
	6bit	invalid															

2.4. RTC

2.4.1. Calibrate abnormally when using both smooth digital calibration and FREQI calibration

Description & impact

Using both smooth digital calibration and FREQI calibration will cause calibration result abnormal.

Workarounds

1) Use RTC shift function to replace smooth digital calibration, such as setting A1S bit and configuring appropriate SFS bits to satisfy the accuracy requirement.
2) Use two 16 seconds calibration window to replace one 32 seconds calibration window.

2.5. TIMER

2.5.1. The shadow preloaded value takes effect only on the rising edge of the counter after modification

Description & impact

The preloaded value takes effect only on the rising edge of the counter after modification which may cause problem to pwm applications with high timing requirements.

Workarounds

Not available.

2.5.2. Count error when timer works at single pulse mode

Description & impact

Timer works at single pulse mode and CK_APBx is CK_AHB / 4 and CK_TIMER is CK_AHB / 2, which causes count error.

Workarounds

1) Do not use above clock configuration.
2) Use timer update interrupt to clear error count.

2.6. USART

2.6.1. Mute mode can be waked up as long as the USART_CTL0 register is operated after mute mode is enabled

Description & impact

After mute mode is enabled, the operation on USART_CTL0 register will wake up USART from mute mode.

Workarounds

When mute mode is enabled and USART uses hardware method to detect idle frame wakeup, operation on USART_CTL0 register is not allowed. When mute mode is enabled and USART uses software method to detect idle frame wakeup, operation on USART_CTL0 register only be allowed when need to exit mute mode.

2.7. I2C

2.7.1. I2C_FCTL register is only configurable on GD32F470xx

Description & impact

The filter control register (I2C_FCTL) is only configurable on GD32F470xx but not on GD32F425xx or GD32F427xx.

Workarounds

Not available.

2.8. SDIO

2.8.1. Do not support low power mode

Description & impact

SDIO_CLK can not be closed automatically in bus idle state when CLKPWRSAV is set in SDIO_CLKCTL register.

Workarounds

Not available.

2.9. EXMC

2.9.1. Auto refresh function of SDRAM controller is influenced by other EXMC controller

Description & impact

Auto refresh function of SDRAM controller is influenced by other EXMC controller. When SDRAM controller execute auto refresh command, if the SDRAM bank is active, the precharge command shall be generated, which need EXMC_A10 port be 1. At that time, EXMC_A10 port is used in other EXMC controller, then the SDRAM auto refresh command execute abnormally which lead SDRAM data error.

Workarounds

Not available.

2.10. ENET

2.10.1. Data reception faults in MII mode

Description & impact

ENET_MII_COL / ENET_MII_CRS / ENET_MII_RX_ER pins are floating on MCU and external PHY has no these pins,.which will cause data reception faults.

Workarounds

Configure ENET_MII_COL pin and ENET_MII_RX_ER pin as AF function and keep them low level. The ENET_MII_CRS pin mode and status can be ignored.

2.10.2. Reception data frame is dropped when enable hardware checksum and the header checksum is 0x0000

Description & impact

When enable hardware checksum and header checksum is 0x0000, this frame will be mistaken for error frame and dropped by hardware.

Workarounds

Use software checksum.

2.11. Core

2.11.1. VDIV or VSQRT instructions might not complete correctly when very short ISRs are used

This limitation refers to Arm ID number 776924 in “Cortex-M4 & Cortex-M4 with FPU Software Developers Errata Notice”.

Description & impact

The VDIV and VSQRT instructions take 14 cycles to execute. When an interrupt is taken a VDIV or VSQRT instruction is not terminated, and completes its execution while the interrupt stacking occurs. If lazy context save of floating point state is enabled then the automatic stacking of the floating point context does not occur until a floating point instruction is executed inside the interrupt service routine.

Lazy context save is enabled by default. When it is enabled, the minimum time for the first instruction in the interrupt service routine to start executing is 12 cycles. In certain timing conditions, and if there is only one or two instructions inside the interrupt service routine, then

the VDIV or VSQRT instruction might not write its result to the register bank or to the FPSCR.

The failure occurring conditions are as follows:

1) The floating point unit is enabled.
2) Lazy context saving is not disabled.
3) A VDIV or VSQRT is executed.
4) The destination register for the VDIV or VSQRT is one of s0 - s15.
5) An interrupt occurs and is taken.
6) The interrupt service routine being executed does not contain a floating point instruction.
7) Within 14 cycles after the VDIV or VSQRT is executed, an interrupt return is executed.

A minimum of 12 of these 14 cycles are utilized for the context state stacking, which leaves 2 cycles for instructions inside the interrupt service routine, or 2 wait states applied to the entire stacking sequence (which means that it is not a constant wait state for every access).

In general, this means that if the memory system inserts wait states for stack transactions then this erratum cannot be observed.

The implications of this limitation is that the VDIV or VQSRT instruction does not complete correctly and the register bank and FPSCR are not updated, which means that these registers hold incorrect, out of date, data.

Workarounds

A workaround is only required if the floating point unit is enabled. A workaround is not required if the stack is in external memory.

There are two possible workarounds:

1) Disable lazy context save of floating point state by clearing LSPEN to 0 (bit 30 of the FPCCR at address 0xE000EF34).
2) Ensure that every interrupt service routine contains more than 2 instructions in addition to the exception return instruction.

3. Revision history

Table 3-1. Revision history

Revision No.	Description	Date
1.0	Initial Release	Mar.16 2023
1.1	Update description of chapter 2.8.1	Apr.3 2023
1.2	Update note of chapter 1.2	Apr.6 2023
1.3	1. Add PMU limitation, referring to chapter 2.1.1 2. Add core limitation, referring to chapter 2.11.1	Nov.2 2023

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